# DECLARATION (37 CFR 1.63) FOR UTILITY OR DESIGN APPLICATION USING AN APPLICATION DATA SHEET (37 CFR 1.76)

Electronic Version v11
Stylesheet Version v10

Title of
Invention

PROCESS FOR DEPOSITING BTBAS-BASED SILICON NITRIDE FILMS

As the below named inventors, we declare that:

This declaration is directed to the invention titled: "PROCESS FOR DEPOSITING BTBAS-BASED SILICON NITRIDE FILMS"

We believe that we are the original and first inventors of the subject matter which is claimed and for which a patent is sought;

We have reviewed and understand the contents of the above-identified application, including the claims, as amended by any amendment specifically referred to above;

We acknowledge the duty to disclose to the United States Patent and Trademark Office all information known to us to be material to patentability as defined in 37 CFR 1.56, including for continuation-in-part applications, material information which became available between the filing date of the prior application and the national or PCT International filing date of the continuation-in-part application.

All statements made herein of own knowledge are true, all statements made herein on information and belief are believed to be true, and further that these statements were made with the knowledge that willful false statements and the like are punishable by fine or imprisonment, or both, under 18 U.S.C. 1001, and may jeopardize the validity of the application or any patent issuing thereon.

#### **FULL NAME OF INVENTORS:**

Inventor 1: Yun-Ren Wang	Inventor
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Inventor 3: Hao-Hsiang Chang	Inventor

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Inventor 4: Tsai-Fu Hsiao	Inventor	
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## COMBINED DECLARATION AND POWER OF ATTORNEY

As a below named inventor, I hereby declare that:

I believe I am the sole (if only one name appears below), or joint (if more than one name appears), original and first inventor of the subject matter which is claimed and for which a patent is sought on the invention entitled:

## "PROCESS FOR DEPOSITING BTBAS-BASED SILICON NITRIDE FILMS"

+ The specification for the above	e entitled invention is filed herewith.
The specification for the above	entitled invention was filed previously
with application serial number:	Filing Date:
I hereby state that I have reviewe specification, including the claims, as amo	ed and understand the contents of the above identified ended by any amendment referred to above.
the invention disclosed in this application. Regulations, Section 1.56 (a). I further application to disclose to the Patent and Tr to the patentability of the invention disclose.	information which is material to the patentability of on in accordance with Title 37, Code of Federal acknowledge the duty in any continuation-in-part ademark Office all information known to be material losed in this application, as defined in 1.56, which date of the prior application and the filing date of this
PRIC	DRITY CLAIM
There is no claim of priority	
Claim of priority is based on the	following:
POWER	OF ATTORNEY
application and to transact all related busing	appoint the following attorneies to prosecute this ness in the Patent and Trademark Office: stration# 41,526

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### DECLARATION

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment or both under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued hereon.

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